# IE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s):

Sparrow

Serial No.:

09/991,399

Filed:

November 20, 2001

For:

DISPERSION MANAGEMENT OPTICAL LITHOGRAPHY CRYSTALS FOR BELOW

**160NM OPTICAL** 

LITHOGRAPHY AND METHODS THEREOF

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Assistant Commissioner for Patents Washington, DC 20231

# INFORMATION DISCLOSURE STATEMENT UNDER 37 CFR § 1.97 - 1.98

Pursuant to 37 CFR 1.98, in addition to the references cited in the above-referenced patent application, the Applicants hereby disclose to the United States Patent and Trademark Office the references recorded on the enclosed PTO Form 1449.

Date of Deposit: November 27, 2002

I hereby certify that this paper (along with any paper referred to as being attached or enclosed) is being deposited with the United States Postal Service on the date indicated above with sufficient postage as first class mail in an envelope addressed to the: Commissioner of Patents and Trademarks, Washington, DC 20231

Respectfully submitted,

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LIST OF PATENTS AND PUBLICATIONS FOR APPLICANTS INFORMATION DISCLOSURE STATEMENT '

SP01-339

APPLICANT Sparrow, R. W.

FILING DATE 11/20/01

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BE ASSIGNED TBX

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09/991,399 PE

REFERENCE DESIGNATION U.S. PATENT DOCUMENTS

Evaminer Document Number Date

Examiner Initial		Document Number	Date	Name	Class	Sub- Class	Filing Date if Approp.
	A1	2002/1012497	8/1/02	Sparrow			5/5/00
	A2	2002/0011202	1/31/02	Gianoulakis et al.			9/15/01
•	A3	2,498,186	2/21/50	Stockbarger et al.			
	A4	2,550,173	4/24/51	Swinehart et al.	DEC		
	A5	3,766,080	10/16/73	Swinehart et al.	THE	EIVE	
	A6	3,769,230	10/30/73	Robinson et al.		`	
	A7	3,959,442	5/25/76	Pastor et al.	NOA	2 9 2002	
	A8	4,038,201	7/26/77	Hargreaves		ו מו מייי נ	1
	A9	4,048,514	9/13/77	Haussuehl et al.		7700	
	A10	4,053,572	10/11/77	Moss et al.	0		
	A11	4,101,331	7/18/78	Anderson			
	A12	4,128,589	12/5/78	Pastor et al.			
	A13	5,000,548	3/19/91	Mercado			
	A14	5,039,858	8/13/91	Anderson et al.			
-	A15	5,852,627	12/22/98	Ershov			
	A16	5,856,991	1/5/99	Ershov			
	A17	5,901,163	5/4/99	Ershov			
	A18	5,970,082	10/19/99	Ershov			
	A19	5,978,409	11/2/99	Das et al.			
	A20	5,982,800	11/9/99	Ishihara et al.			
	A21	6,069,749	5/30/00	Omura			
	A22	6,181,480	1/30/01	Ito			
*	A23	6,201,634	3/13/01	Sakuma et al.			
	A24	6,298,080	10/2/01	Heist et al.			
	A25	6,309,461	10/30/01	Gianoulakis et al.			
	A26	6,342,312	1/29/02	Oba et al.			
	A27	6,377,338	4/23/02	Suenaga			4
	A28	6,395,657	5/28/02	Mayolet et al.			
	A29	6,451,111	9/17/02	Beall et al.			

**EXAMINER:** 

DATE CONSIDERED:

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609: draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Information Disclosure Statement-PTO-1449 (Modified)

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FOREIGN PATENT DOCUMENTS

				Sub-	Translation		
	Document Number	Date	Country	Class_	Class	Yes	No
A30	1 006 373 A2	6/7/00	EPC			Х	
 A31	0 875 778 A1	11/4/98	EPC			Х	
A32	0 869 203 B1	8/22/01	EPC M			Х	
A33	0 942 297	9/15/99	EPC			X	<u> </u>
A34	1 130 419 A2	9/5/01	EPC No.	1/		X	1
A35	1 139 138 B1	10/4/01	EPC	2 9 2002	)	Х	<u> </u>
A36	1 291 321	3/27/69	German	7 - 5005		Х	
 A37	222 426 A1	5/15/98	Germany	1/00		X	
A38	09-315894	12/9/97	JAPAN			. X	<u> </u>
A39	10[1998]-59799	3/3/98	Japan			X	<u> </u>
A40	10[1998]-1310	1/6/98	Japan			X	
A41	99/46836	9/16/99	PCT			X	
A42	01/37052 A1	5/25/01	PCT			X	
 . A43	00/75697 A1	12/14/00	PCT .			Х	
 A44	02/31232	4/18/02	PCT			Х	
 A45	01/01182	1/4/01	PCT			Х	L.
 A46	0 942 297 A2	9/15/99	PCT			Х	
A47	91/11734	8/8/91	PCT			Х	

**EXAMINER:** 

DATE CONSIDERED:

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#### ATTORNEY DOCKET NO. SERIAL NO. FORM PTO-1449 (MODIFIED) 09/991,389 \ P E SP01-339 LIST OF PATENTS AND PUBLICATIONS FOR APPLICANTS INFORMATION NOV 2 7 2002 APPLICANT Sparrow, R. W. DISCLOSURE STATEMENT TBACK FRAD **GROUP TO** BE ASSIGNED FILING DATE 11/20/01 OTHER ART (Including Author, Title, Date, Pertinent Pages, etc.) "Growth and Properties of Scintillating Crystals BaF2." Jiang et al., Journal of Crystal Growth. **A48** vol. 79, no. 1-3, December 1986, pages 720-722 "Modern Optical Engineering-The Design of Optical Systems," Warren J. Smith, Modern Opt A49 Eng. McGraw-Hill Book Company, 1966, Article: "Optical Materials and Coatings," pp 145-161; Article: "The Design of Optical Systems: General," pp 326-355. A50 U.S. Serial No. 09/327,043, filed June 7, 1999, Gianoulakis et al., Crystal Growth and Annealing Method and Apparatus, pages 1-21 OPTOVAC, Optical Crystal Handbook, January 1993, pages 1-41 A51 "Optical Characteristics of Large Single Crystals of Fluorides", Chernevskaya, E.G., et al., Opt. A52 Technol. (USSR), June 1973, Vol. 40, No. 6 pages 379-380 Svetlto, O, "Principles of Lasers:, 3rd Ed., 1989, pp.330-331 A53 Lambda Physik webpage: www.lambdaphysik.com/Microlithography/fullstory.asp?news\_id=22, A54 Lithography News, Lambda Physik Ships Fifth 157nm Lithography Laser, page 1 Lambda Physik webpage: www.lambdaphysik.com/Microlithography/novaline.asp, Novaline ® A55 Lithography Series, pages 1-2. Lambda Physik webpage: www.lambdaphysik.com/Microlithography/mooreslaw.asp, A56 Lithography - History, Moore's Law, pages 1-3. "Lambda Physik Fourth Annual 157nm/EUV Symposium" website: A57 http://www.lambdaphysik.com/microlithography/157. (printed out 11/01) Lambda Physik webpage: www.lambdaphysik.com/Microlithography/fullstory.asp, Lithography A58 News, Lambda Physik Announces Breakthrough in 157 nm F2 Lithography, pages 1-2. "Spatial Dispersion in the Dielectric Constant of GaAs," Yu et al., Solid State Comm, Vol. 9, pp. A59 1421-1424, 1971. "Technology at a Glance-Fall 2001," Website: http://www.nist.gov/public\_affairs/taglance/ A60 taq01fall/fall2001.htm, pp 1-11. "Semicon West 2001," Website: http://www.nist.gov/public affairs/factsheet/ A61 semiconwest01.htm "Metrology Supporting Deep Ultraviolet Lithography." Website:http://www.eeel.nist.gov/810.0 A62 /lithography deep.html, published June 2001, Ofc of Microelectronic Programs. "Minimizing Spatial-dispersion-induced birefringence in crystals used for precision optics by A63 using mixed crystals of materials with the opposite sign of the birefringence." Website: http://physics.nist.gov/Divisions/Div842/Gp3/DUVMatChar/birefring.html. updated 8/1/01. "The Trouble with Calcium Fluoride." SPIEs oeMagazine, pp 23-25, March 2002. A64 A65 "Ca<sub>1-x</sub>Ba<sub>x</sub>F<sub>2</sub> and Ca<sub>1-x</sub>Sr<sub>x</sub>F<sub>2</sub> Mixed Crystals as potential solution to intrinsic birefringence problem for 157nm lithography," Burnett et al., SEMATECH 157nm Tech Data Rev, 12/11/01, NIST. "Stress-Optical coefficients of 157nm Materials," Burnett et al., SEMATECH 157nm Tech Data A66 Rev, 12/11/01, NIST. "Intrinsic Birefringence in 157nm Materials," Burnett et al., 2<sup>nd</sup> Int'l Symposium on 157nm A67 Lithography, 5/15/01, NIST. A68 NIST updates for July 9, 2001, website: http://www.nist.gov/public affairs/update/ upd010709.htm, pp 1-8. "Electron and Optical Physics Division" website: http://physics.nist.gov/TechAct/Div841/div A69 841h.html, Tech Activities 2001, pp 1-9. "Atomic Physics Division" website: http://physics.nist.gov/TechAct/Div842/div842h.html, Tech A70

### **EXAMINER:**

#### DATE CONSIDERED:

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609: draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

Activities 2001, pp 1-17.

FORM PTC	0-1449 (MODIFIED)	ATTORNEY DOCKET NO.	SERIAL NO.				
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LIST OF PATEN	TS AND PUBLICATIONS		\(\sigma\)				
	ANTS INFORMATION						
DISCLOSI	JRE STATEMENT	APPLICANT Sparrow, R. W.	NOV 2 7 200				
		FILING DATE 11/20/01	BE ASSIGNED TRA				
	OTHER ART (Including /	Author, Title, Date, Pertinent Pages	, etc.) CONTINUED				
A71	"Plasma Radiation	"Plasma Radiation Group; DUV Sources and Materials Characterization" website:					
		nist.gov/Divisions/Div 842/Gp3/DIVMatChar/index.html., pp 1-2.					
A72	1	"Absolute refractive indices and thermal coefficients of fused silica and calcium fluoride near 193 nm," <i>Appl Optics</i> , Vol. 37, No. 25, 9/1/98, pp 5964-5968.					
A73	"Intrinsic Birefringe 241102(r), pp 1-4	"Intrinsic Birefringence in calcium fluoride and barium fluoride," <i>Phys Review B</i> , Vol. 64, 241102(r), pp 1-4					
A74	1	"Polarizability of Fluoride Ions in Fluorides with Fluorite-type structure" Sorokin, N.I., Crystallography Reports, Vol. 45, No. 6, 2000, pp 976-978.					
A75	"Optical Anisotropy	"Optical Anisotropy of Silicon Single Crystals" Pastrnak et al., <i>Phys Review B</i> , Vol. 3, No. 8, 15 April 1971, pp 2567-2571.					
A76		Barium Fluoride and Magnesium Fluoride Product Information, ISP Corp, www.ispoptics.com					
A77	Barium Fluoride Pa	Barium Fluoride Patinal product info, EM Industries, website: www.emicoe.com/barfluor.cfm					
A78		"Materials Problem snags 157nm lithography" <i>EETimes</i> website: www.eetimes.com/story /OEG20010720S0106, July 20, 2001, 4 pages.					
A79		hift to 157nm lithography" <i>EETime</i> 010, May 18, 2000, 4 pages.	s website: ww.eetimes.com/story				

**EXAMINER:** 

## DATE CONSIDERED:

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609: draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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